

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

2SB1375

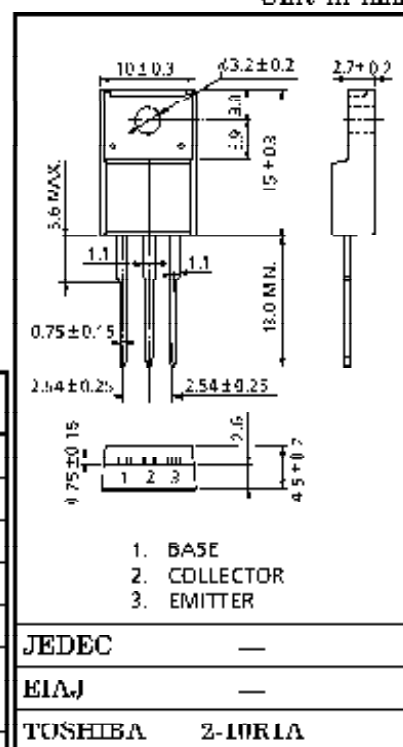
AUDIO FREQUENCY POWER AMPLIFIER

Unit in mm

- Low Saturation Voltage : $V_{CE(sat)} = -1.5V$ (Max.)
($I_C = -2A$, $I_B = -0.2A$)
- High Power Dissipation : $P_C = 25W$ ($T_a = 25^\circ C$)
- Collector Metal (Fin) is Covered with Mold Resin
- Complementary to 2SD2012

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CB0}	-60	V
Collector-Emitter Voltage	V_{CE0}	-60	V
Emitter-Base Voltage	V_{EB0}	7	V
Collector Current	I_C	-3	A
Base Current	I_B	-0.5	A
Collector Power Dissipation	P_C	2.0 25	W
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55~150	$^\circ C$



Weight : 1.7g

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CB0}	$V_{CB} = -60V$, $I_E = 0$	—	—	-10	μA
Emitter Cut off Current	I_{EB0}	$V_{EB} = 7V$, $I_C = 0$	—	—	10	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CE0}$	$I_C = -50mA$, $I_B = 0$	-60	—	—	V
DC Current Gain	$h_{FE(1)}$	$V_{CE} = -5V$, $I_C = -0.5A$	100	—	320	
	$h_{FE(2)}$	$V_{CE} = -5V$, $I_C = -2A$	15	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -2A$, $I_B = -0.2A$	—	-1.0	-1.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -5V$, $I_C = -0.5A$	—	-0.75	-1.0	V
Transition Frequency	f_T	$V_{CE} = -5V$, $I_C = -0.5A$	—	9	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V$, $I_E = 0$, $f = 1MHz$	—	60	—	pF

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